NSN 5961-01-048-7658

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-048-7658 **Inclosure Material:** Metal **Overall Length:** 2.390 inches **Overall Diameter:** 0.312 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud and unthreaded hole Thready Qty Per Inch (tpi): 36 **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 reverse voltage, dc **Current Rating Per Characteristic:** 0.50 amperes source cutoff current preset **Power Rating Per Characteristic:** 0.5 watts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius ambient air **Thread Series Designator:** Uns **Terminal Type And Quantity:** 1 threaded hole and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Demilitarizat No

Fiig: A110a0